

### PRELIMINARY

#### Features

- High power
  - $P_o = 35$  dBm at  $P_{in} = 4$  dBm
- Super low distortion
  - $P_{adj} = -67$  dBc at  $P_o = 34$  dBm, 600 kHz offset
- High gain
  - $G_p = 31$  dB at  $P_{in} = 4$  dBm
- Input/output port matched to  $50\Omega$
- Hermetically sealed package

#### RF Performance Specifications ( $T_a = 25^\circ\text{C}$ )

Characteristic	Symbol	Condition	Unit	Min.	Typ.	Max.
Output Power	$P_o$	$V_{DD1} = V_{DD2} = V_{DD3} = 9V$ $V_{GG} = -5V, f = 1.9$ GHz $P_{in} = 4$ dBm	dBm	34	35	-
Power Gain	$G_p$		dB	30	31	-
Drain Current	$I_{DD}^*$		A	-	1.5	1.9
Adjacent Channel Leakage Power	$P_{adj}$	$V_{DD1} = V_{DD2} = V_{DD3} = 9V$ $V_{GG} = -5V, f = 1.9$ GHz $P_o = 34$ dBm $\pi / 4$ -QPSK Modulation 600 kHz Offset	dBc	-	-67	-65

\* $I_{DD} = I_{DD1} + I_{DD2} + I_{DD3}$

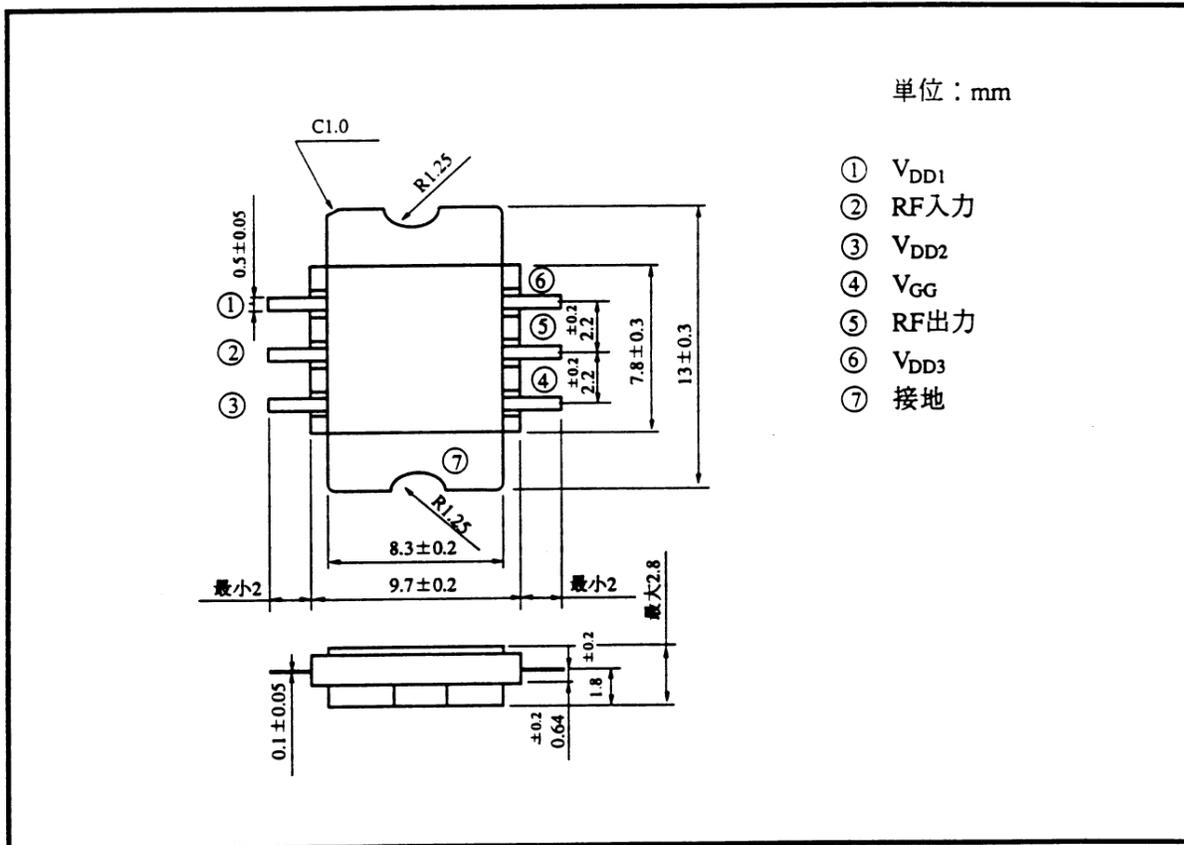
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Absolute Maximum Ratings (T<sub>a</sub> = 25°C)

Characteristic	Symbol	Unit	Rating
Drain Supply Voltage	V <sub>DD1</sub> , V <sub>DD2</sub> , V <sub>DD3</sub>	V	15
Gate Supply Voltage	V <sub>GG</sub>	V	-15
Input Power	P <sub>in</sub>	dBm	13
Flange Temperature	T <sub>f</sub>	°C	-30 ~ +80
Storage Temperature	T <sub>stg</sub>	°C	-65 ~ +175

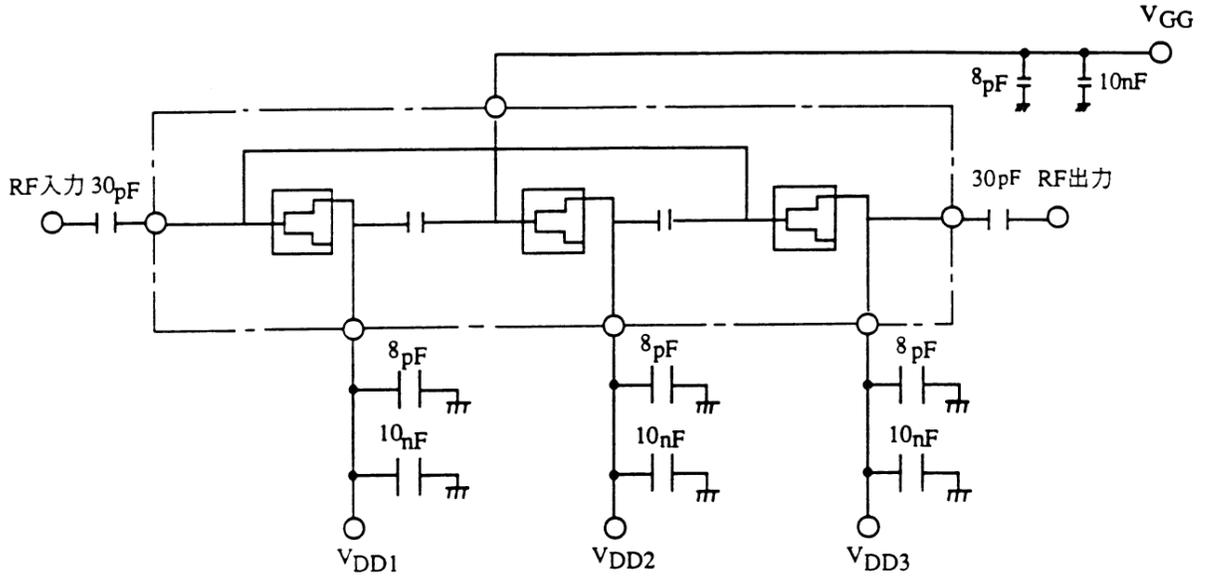
Package Outline (2-8N1B)



Handling Precautions for Packaged Type

Soldering iron should be grounded and the operating time should not exceed 10 seconds at 260°C.

MMIC Schematic



RF Performance

